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Thyristor High Voltage, Phase Control SCR, 40 A



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PRIMARY CHARACTERISTICS					
I _{T(AV)}	35 A				
V _{DRM} /V _{RRM}	1600 V				
V _{TM}	1.45 V				
I _{GT}	150 mA				
TJ	-40 °C to +125 °C				
Package	TO-247AD 3L				
Circuit configuration	Single SCR				

FEATURES

- AEC-Q101 qualified meets JESD 201 class 1A whisker test
- Flexible solution for reliable AC power rectification



COMPLIANT HALOGEN

- Easy control peak current at charger power up to reduce passive / electromechanical components
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- On-board and off-board EV / HEV battery chargers
- Renewable energy inverters

DESCRIPTION

The VS-40TPS16LHM3 high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications.

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
I _{T(AV)}	Sinusoidal waveform	35	٨			
I _{RMS}		55	— A			
V _{RRM} /V _{DRM}		1600	V			
I _{TSM}		500	A			
V _T	40 A, T _J = 25 °C	1.45	V			
dv/dt		1000	V/µs			
di/dt		100	A/µs			
TJ		-40 to +125	°C			

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} / V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} / I _{DRM} AT 125 °C mA				
VS-40TPS16LHM3	1600	1700	10				



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SYMBOL	TEST CONDITIONS		VALUES	UNITS
I _{T(AV)}	$T_C = 79$ °C, 180° conduction half sine wave	;	35	
I _{T(RMS)}		55	A	
	10 ms sine pulse, rated V_{RRM} applied		420	
ITSM	10 ms sine pulse, no voltage reapplied		500	
121	10 ms sine pulse, rated V _{RRM} applied		880	A2-
1-1	10 ms sine pulse, no voltage reapplied	ij – ijiliax.	1250	A ² s
l²√t	t = 0.1 ms to 10 ms, no voltage reapplied		12 500	A²√s
V _{T(TO)1}			1.02	V
V _{T(TO)2}	T 405.00		1.23	
r _{t1}	$1_{\rm J} = 125 {}^{-}{\rm C}$		9.74	mΩ
r _{t2}			7.50	
N	110 A, T _J = 25 °C		1.92	v
VTM	90 A, T _J = 25 °C		1.82	V
dl/dt	T _J = 25 °C	100	A∕µs	
I _H	Anode supply = 6 V, resistive load, initial T_J = 1 A, I_T = 25 °C			
١L	Anode supply = 6 V, resistive load, $T_J = 25 \text{ °C}$		350	
	T _J = 25 °C		0.5	mA
I _{RRM} /I _{DRM}	$T_J = 125 \text{ °C}$ $V_R = \text{rated } V_{RRM}/V_{DR}$	$V_{\rm R}$ = rated $V_{\rm RRM}/V_{\rm DRM}$		
dV/dt	$T_J = T_J$ maximum, linear to 80 % V_{DRM} , R_g -	k = open	1000	V/µs
	$\begin{tabular}{ c c c c c } \hline & & & & & & & & & \\ \hline & & & & & & & &$	$\begin{tabular}{ c c c c c } \hline SYMBOL & TEST CONDITIONS \\ \hline I_{T(AV)} & T_C = 79 \ ^{\circ}C, 180 \ ^{\circ} \ conduction half sine wave \\ \hline I_{T(RMS)} & \\ \hline I_{T(RMS)} & \\ \hline I_{TSM} & \hline 10 \ ms \ sine \ pulse, \ rated \ V_{RRM} \ applied \\ \hline 10 \ ms \ sine \ pulse, \ no \ voltage \ reapplied \\ \hline 10 \ ms \ sine \ pulse, \ rated \ V_{RRM} \ applied \\ \hline 10 \ ms \ sine \ pulse, \ no \ voltage \ reapplied \\ \hline 10 \ ms \ sine \ pulse, \ no \ voltage \ reapplied \\ \hline 10 \ ms \ sine \ pulse, \ no \ voltage \ reapplied \\ \hline 10 \ ms \ sine \ pulse, \ no \ voltage \ reapplied \\ \hline I^2 t & t = 0.1 \ ms \ to \ 10 \ ms, \ no \ voltage \ reapplied \\ \hline V_{T(TO)1} & \\ \hline V_{T(TO)2} & \\ \hline V_{T(TO)2} & \\ \hline V_{T(TO)2} & \\ \hline r_{t2} & \hline 110 \ A, \ T_J = 25 \ ^{\circ}C & \\ \hline V_{TM} & \hline 110 \ A, \ T_J = 25 \ ^{\circ}C & \\ \hline I_H & Anode \ supply = 6 \ V, \ resistive \ load, \ initial \ T_J \\ \hline I_L & Anode \ supply = 6 \ V, \ resistive \ load, \ T_J = 25 \ ^{\circ}C & \\ \hline I_{RRM/IDRM} & \hline T_J = 25 \ ^{\circ}C & \\ \hline V_R = \ rated \ V_{RRM}/V_{DR} & \\ \hline \end{array}$	$\begin{tabular}{ c c c c } \hline \mathbf{SYMBOL} & $\mathbf{T}_{C} = 79 \ ^{\circ}C, 180^{\circ}$ conduction half sine wave $$$ $$ $$ $$ $$ $$ $$ $$ $$ $$ $$ $$ $$	$\begin{tabular}{ c c c c } \hline $YMBOL$ & $TEST CONDITIONS$ & $VALUES$ \\ \hline $I_{T(AV)$}$ $T_C = 79 °C, 180° conduction half sine wave$ & 35 \\ \hline $I_{T(RMS)$}$ & 55 \\ \hline $I_{T(RMS)$}$ & 55 \\ \hline $I_{T(RMS)$}$ & 10 ms sine pulse, rated V_{RRM} applied$ \\ \hline $I0$ ms sine pulse, no voltage reapplied$ & $I10$ ms sine pulse, no voltage reapplied$ \\ \hline $I^2 \ 10 ms sine pulse, no voltage reapplied$ & $I10$ ms sine pulse, no voltage reapplied$ & $I10$ ms sine pulse, no voltage reapplied$ & $I250$ & 1250 $

TRIGGERING							
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS			
Maximum peak gate power	P _{GM}			10	W		
Maximum average gate power	P _{G(AV)}			2.5	vv		
Maximum peak gate current	I _{GM}			2.5	А		
Maximum peak negative gate voltage	- V _{GM}			10	V		
	V _{GT}	$T_J = -40 \ ^{\circ}C$	Anode supply = 6 V resistive load	4.0			
Maximum required DC gate voltage to trigger		T _J = 25 °C		2.5	V		
		T _J = 125 °C		1.7			
		T _J = -40 °C		270			
Maximum required DC gate current to trigger	I _{GT}	T _J = 25 °C	Anode supply = 6 V resistive load	150	mA		
		T _J = 125 °C		80			
Maximum DC gate voltage not to trigger	V _{GD}	T 105 °C V reted	0.25	V			
Maximum DC gate current not to trigger	I _{GD}	$T_J = 125 \text{ °C}, V_{DRM} = \text{rated value}$		6	mA		

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Document Number: 96134



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THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +125	°C			
Maximum thermal resistance, junction to case R _{thJC}		DC operation	0.6				
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	40	°C/W			
Maximum thermal resistance, case to heat sink	R _{thCS}	Mounting surface, smooth, and greased	0.2				
Approximate weight			6	g			
Approximate weight			0.21	oz.			
Mounting torgueminimum			6 (5)	kgf · cm			
maximum			12 (10)	(lbf · in)			
Marking device		Case style TO-247AD 3L	40TPS1	6LH			

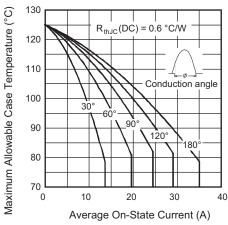
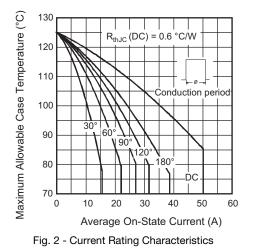
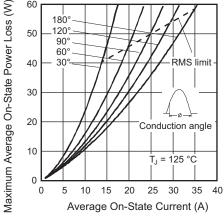


Fig. 1 - Current Rating Characteristics





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Fig. 3 - On-State Power Loss Characteristics

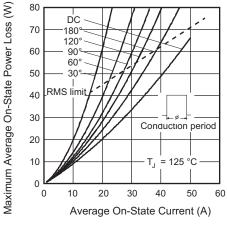
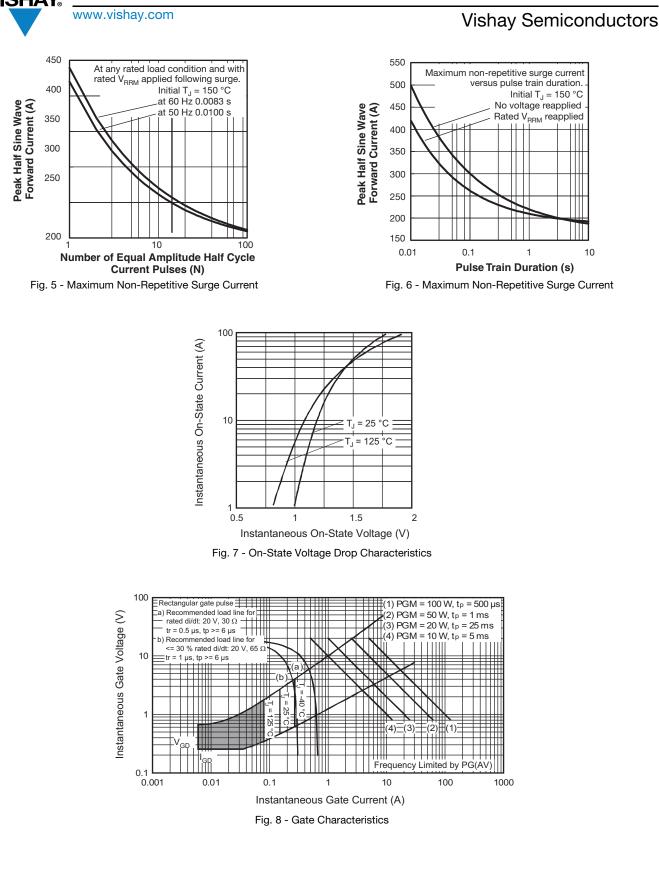
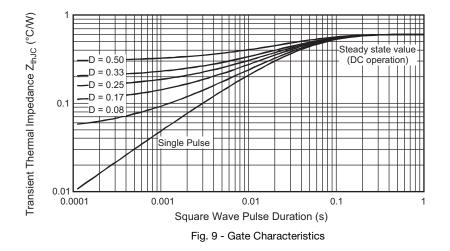


Fig. 4 - On-State Power Loss Characteristics



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ORDERING INFORMATION TABLE

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ISHAY

Device code	VS-	40	т	Р	S	16	L	н	М3
	1	2	3	4	5	6	7	8	9
	1 .	- Visł	nay Sem	niconduc	tors pro	duct			
	2 -	Cur	rent rati	ng (40 =	40 A)				
	3 -	Circ	uit conf	iguratior	1:				
		T =	thyristo	r					
	4	Pac	kage:						
		P =	TO-247						
	5 -	. Тур	e of silio	con:					
		S =	standar	d recove	ery rectif	ier	г		
	6	· Volt	age rati	ngs —				16 = 16	600 V
	7 -	L=	long lea	lds			_		
	8	• H =	AEC-Q	101 qua	lified				
	9 -	- Env	vironmer	ntal digit:					
		М3	= halog	en-free,	RoHS-c	ompliar	nt, and t	erminat	ions lea

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-40TPS16LHM3	25	500	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS				
Dimensions TO-247AD 3L www.vishay.com/doc?95626				
Part marking information TO-247AD 3L www.vishay.com/doc?95007				

Revision: 23-Feb-18

Document Number: 96134

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TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

(2, 52, 51) (4) Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	5 BSC	
ØК	0.2	254	0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	' BSC	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

- ⁽³⁾ Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- ⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

 Revision: 06-Mar-2020
 1
 Document Number: 95626

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Revision: 01-Jan-2024